# Automotive N-Channel 100 V (D-S) 175 °C MOSFET

| PRODUCT SUMMARY | |
|---|---|
| $V_{DS}$ (V) | 100 |
| $R_{DS(on)}$ (Ω) at $V_{GS}$ = 10 V | 0.025 |
| $R_{DS(on)}$ (Ω) at $V_{GS}$ = 4.5 V | 0.029 |
| $I_D$ (A) | 40 |
| Configuration | Single |
| Package | TO-252 Reverse Lead DPAK |

## FEATURES

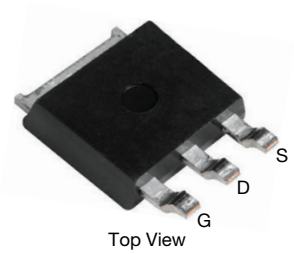
- TrenchFET® power MOSFET
- Package with low thermal resistance
- 100 % $R_g$ and UIS tested
- AEC-Q101 qualified
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

AUTOMOTIVE GRADE

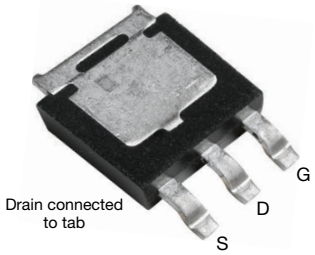
RoHS COMPLIANT

HALOGEN FREE

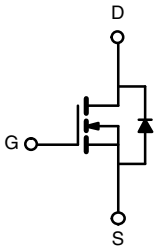
**TO-252 Reverse Lead DPAK**




Top View




Bottom View




N-Channel MOSFET

| ABSOLUTE MAXIMUM RATINGS ($T_C$ = 25 °C, unless otherwise noted) | | | | |
|---|---|---|---|---|
| PARAMETER | | SYMBOL | LIMIT | UNIT |
| Drain-Source Voltage | | $V_{DS}$ | 100 | V |
| Gate-Source Voltage | | $V_{GS}$ | ± 20 | |
| Continuous Drain Current | $T_C$ = 25 °C [a] | $I_D$ | 40 | A |
| | $T_C$ = 125 °C | | 26 | |
| Continuous Source Current (Diode Conduction) [a] | | $I_S$ | 40 | |
| Pulsed Drain Current [b] | | $I_{DM}$ | 160 | |
| Single Pulse Avalanche Current | L = 0.1 mH | $I_{AS}$ | 40 | |
| Single Pulse Avalanche Energy | | $E_{AS}$ | 80 | mJ |
| Maximum Power Dissipation [b] | $T_C$ = 25 °C | $P_D$ | 136 | W |
| | $T_C$ = 125 °C | | 45 | |
| Operating Junction and Storage Temperature Range | | $T_J$, $T_{stg}$ | -55 to +175 | °C |

| THERMAL RESISTANCE RATINGS | | | | |
|---|---|---|---|---|
| PARAMETER | | SYMBOL | LIMIT | UNIT |
| Junction-to-Ambient | PCB Mount [c] | $R_{thJA}$ | 50 | °C/W |
| Junction-to-Case (Drain) | | $R_{thJC}$ | 1.1 | |

**Notes**

a. Package limited.
b. Pulse test; pulse width ≤ 300 µs, duty cycle ≤ 2 %.
c. When mounted on 1" square PCB (FR4 material).



For technical questions, contact: automostechsupport@vishay.com

THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT www.vishay.com/doc?91000

| **SPECIFICATIONS** ($T_C$ = 25 °C, unless otherwise noted) | | | | | | | |
|---|---|---|---|---|---|---|---|
| **PARAMETER** | **SYMBOL** | **TEST CONDITIONS** | | **MIN.** | **TYP.** | **MAX.** | **UNIT** |
| **Static** | | | | | | | |
| Drain-Source Breakdown Voltage | $V_{DS}$ | $V_{GS}$ = 0 V, $I_D$ = 250 µA | | 100 | - | - | V |
| Gate-Source Threshold Voltage | $V_{GS(th)}$ | $V_{DS}$ = $V_{GS}$, $I_D$ = 250 µA | | 1.5 | - | 2.5 | |
| Gate-Source Leakage | $I_{GSS}$ | $V_{DS}$ = 0 V, $V_{GS}$ = ± 20 V | | - | - | ± 100 | nA |
| Zero Gate Voltage Drain Current | $I_{DSS}$ | $V_{GS}$ = 0 V | $V_{DS}$ = 100 V | - | - | 1 | µA |
| | | $V_{GS}$ = 0 V | $V_{DS}$ = 100 V, $T_J$ = 125 °C | - | - | 50 | |
| | | $V_{GS}$ = 0 V | $V_{DS}$ = 100 V, $T_J$ = 175 °C | - | - | 250 | |
| On-State Drain Current [a] | $I_{D(on)}$ | $V_{GS}$ = 10 V | $V_{DS}$ ≥ 5 V | 50 | - | - | A |
| Drain-Source On-State Resistance [a] | $R_{DS(on)}$ | $V_{GS}$ = 10 V | $I_D$ = 40 A | - | 0.019 | 0.025 | Ω |
| | | $V_{GS}$ = 10 V | $I_D$ = 40 A, $T_J$ = 125 °C | - | - | 0.050 | |
| | | $V_{GS}$ = 10 V | $I_D$ = 40 A, $T_J$ = 175 °C | - | - | 0.063 | |
| | | $V_{GS}$ = 4.5 V | $I_D$ = 20 A | - | 0.021 | 0.029 | |
| Forward Transconductance [b] | $g_{fs}$ | $V_{DS}$ = 15 V, $I_D$ = 40 A | | - | 73 | - | S |
| **Dynamic [b]** | | | | | | | |
| Input Capacitance | $C_{iss}$ | $V_{GS}$ = 0 V | $V_{DS}$ = 25 V, f = 1 MHz | - | 2703 | 3380 | pF |
| Output Capacitance | $C_{oss}$ | | | - | 312 | 390 | |
| Reverse Transfer Capacitance | $C_{rss}$ | | | - | 127 | 160 | |
| Total Gate Charge [c] | $Q_g$ | $V_{GS}$ = 10 V | $V_{DS}$ = 50 V, $I_D$ = 40 A | - | 46 | 70 | nC |
| Gate-Source Charge [c] | $Q_{gs}$ | | | - | 8.2 | - | |
| Gate-Drain Charge [c] | $Q_{gd}$ | | | - | 13 | - | |
| Gate Resistance | $R_g$ | f = 1 MHz | | 0.9 | 1.8 | 3.1 | Ω |
| Turn-On Delay Time [c] | $t_{d(on)}$ | $V_{DD}$ = 50 V, $R_L$ = 1.25 Ω<br>$I_D$ ≅ 40 A, $V_{GEN}$ = 10 V, $R_g$ = 1 Ω | | - | 11 | 17 | ns |
| Rise Time [c] | $t_r$ | | | - | 11 | 17 | |
| Turn-Off Delay Time [c] | $t_{d(off)}$ | | | - | 27 | 41 | |
| Fall Time [c] | $t_f$ | | | - | 6 | 9 | |
| **Source-Drain Diode Ratings and Characteristics [b]** | | | | | | | |
| Pulsed Current [a] | $I_{SM}$ | | | - | - | 160 | A |
| Forward Voltage | $V_{SD}$ | $I_F$ = 40 A, $V_{GS}$ = 0 V | | - | 0.9 | 1.5 | V |

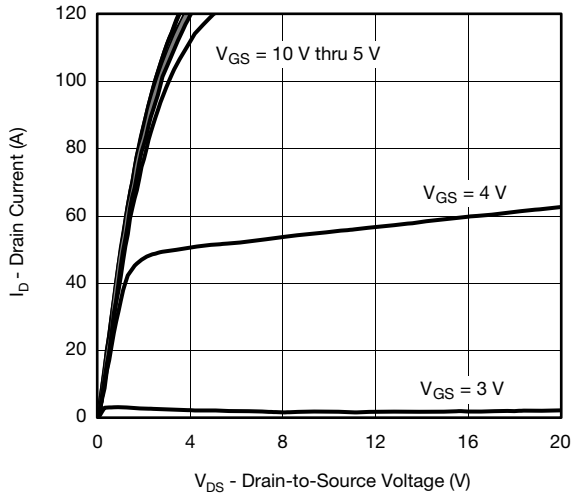
**Notes**

a. Pulse test; pulse width ≤ 300 µs, duty cycle ≤ 2 %.
b. Guaranteed by design, not subject to production testing.
c. Independent of operating temperature.

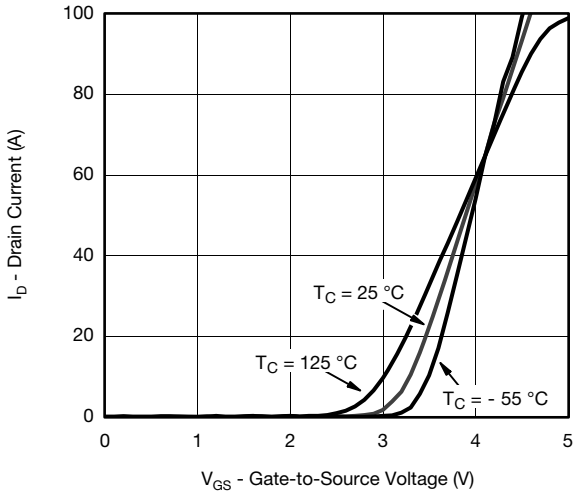
*Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.*


For technical questions, contact: automostechsupport@vishay.com
THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT www.vishay.com/doc?91000

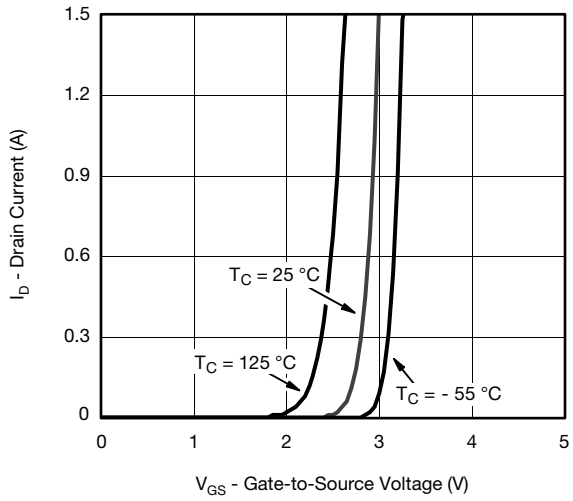
## TYPICAL CHARACTERISTICS ($T_A$ = 25 °C, unless otherwise noted)



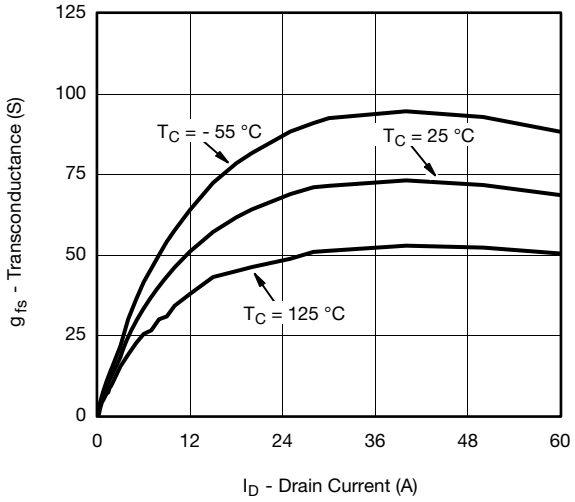

**Output Characteristics**



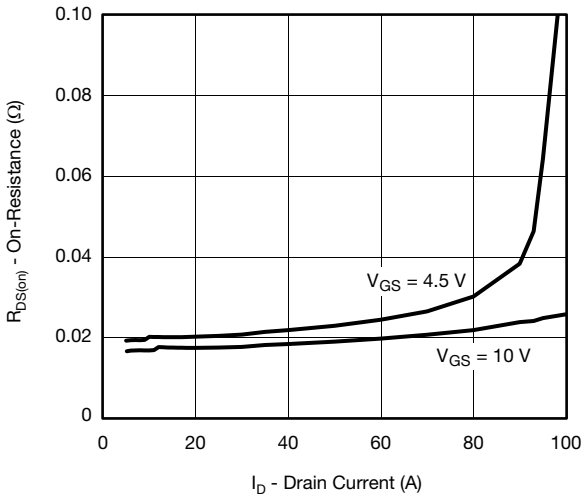

**Transfer Characteristics**



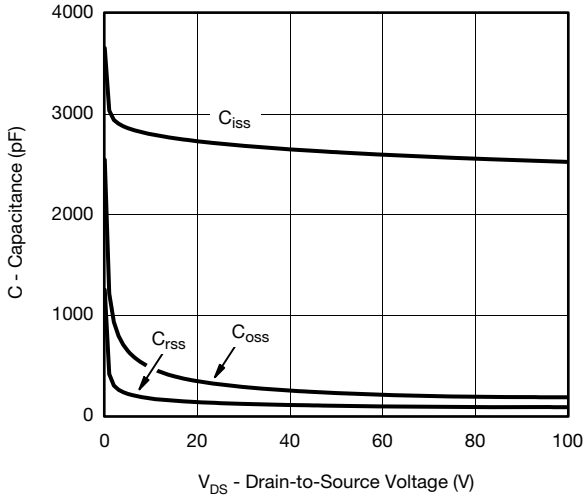

**Transfer Characteristics**




**Transconductance**




**On-Resistance vs. Drain Current**



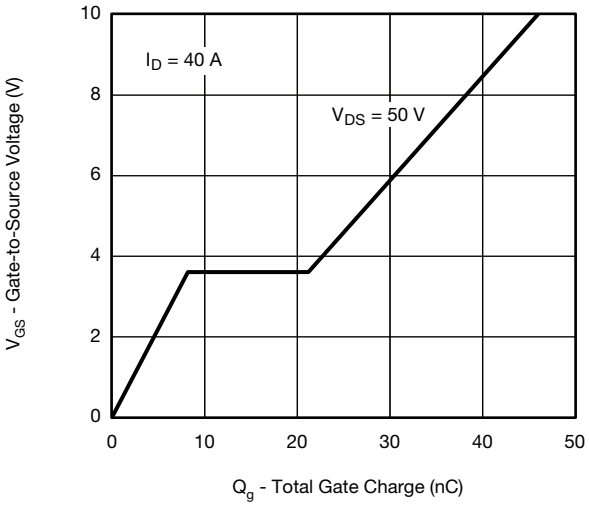

**Capacitance**



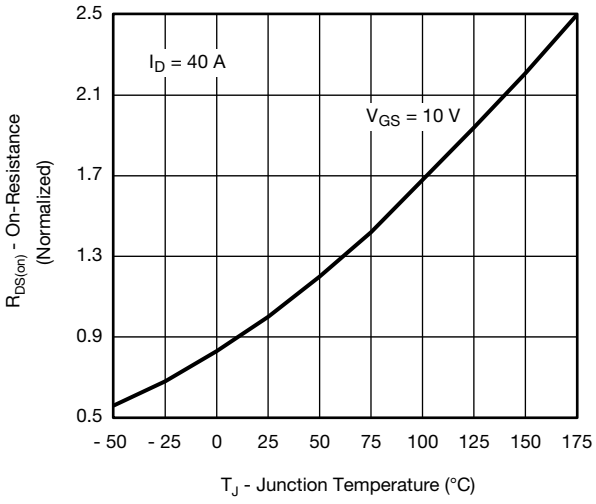
For technical questions, contact: automostechsupport@vishay.com

THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT www.vishay.com/doc?91000

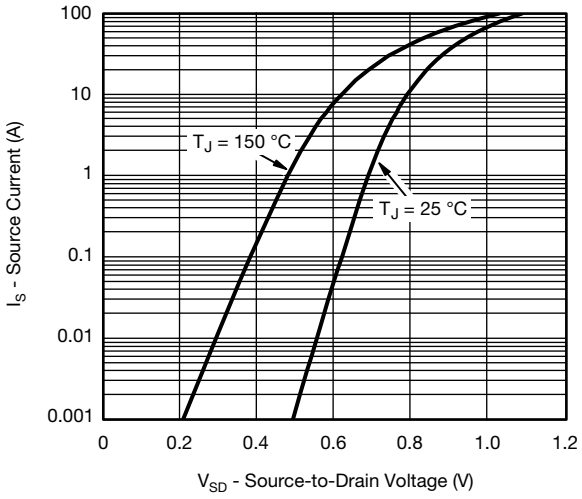
## TYPICAL CHARACTERISTICS ($T_A$ = 25 °C, unless otherwise noted)



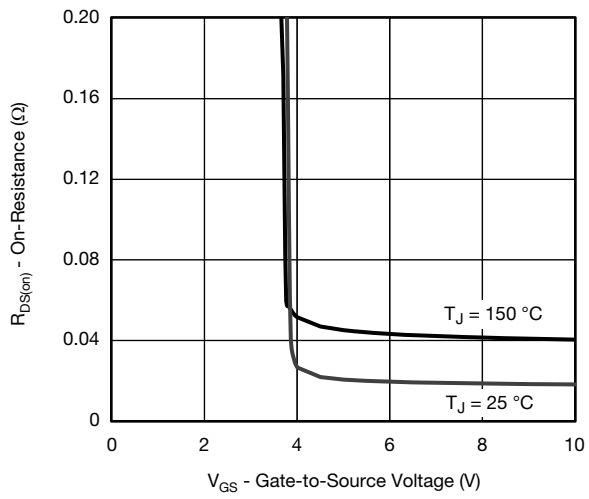

**Gate Charge**



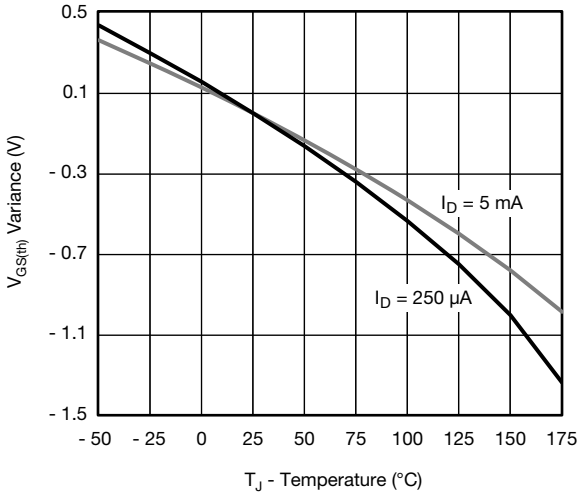

**On-Resistance vs. Junction Temperature**



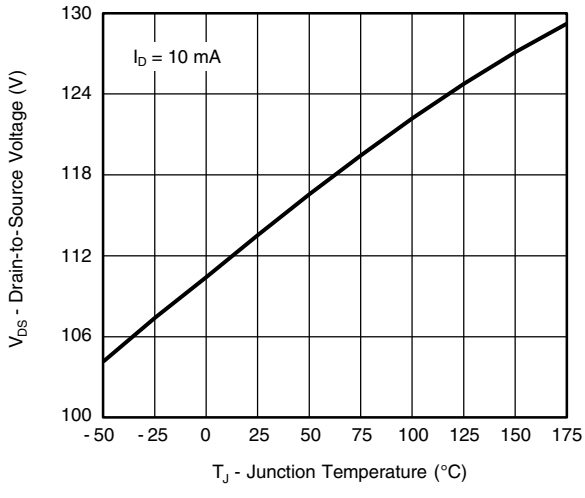

**Source Drain Diode Forward Voltage**




**On-Resistance vs. Gate-to-Source Voltage**



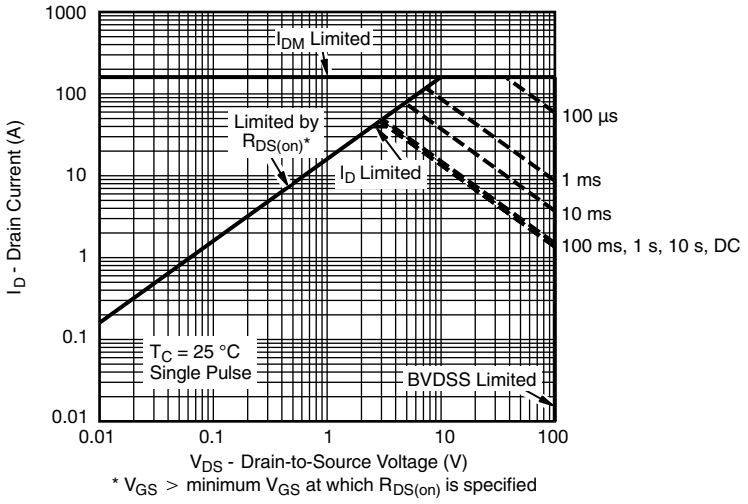

**Threshold Voltage**



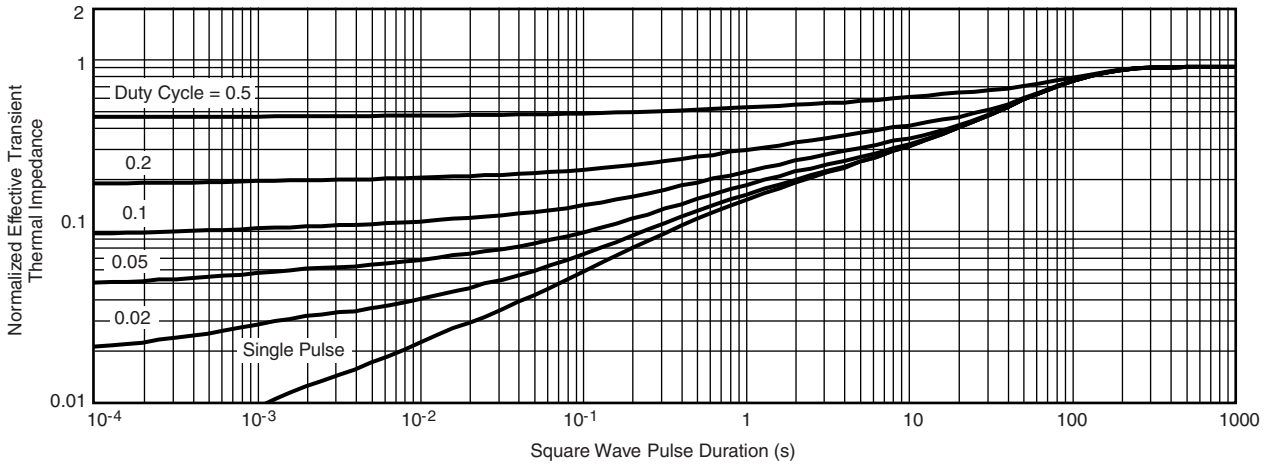

**Drain Source Breakdown vs. Junction Temperature**


For technical questions, contact: automostechsupport@vishay.com
THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT www.vishay.com/doc?91000

**THERMAL RATINGS** ($T_A$ = 25 °C, unless otherwise noted)



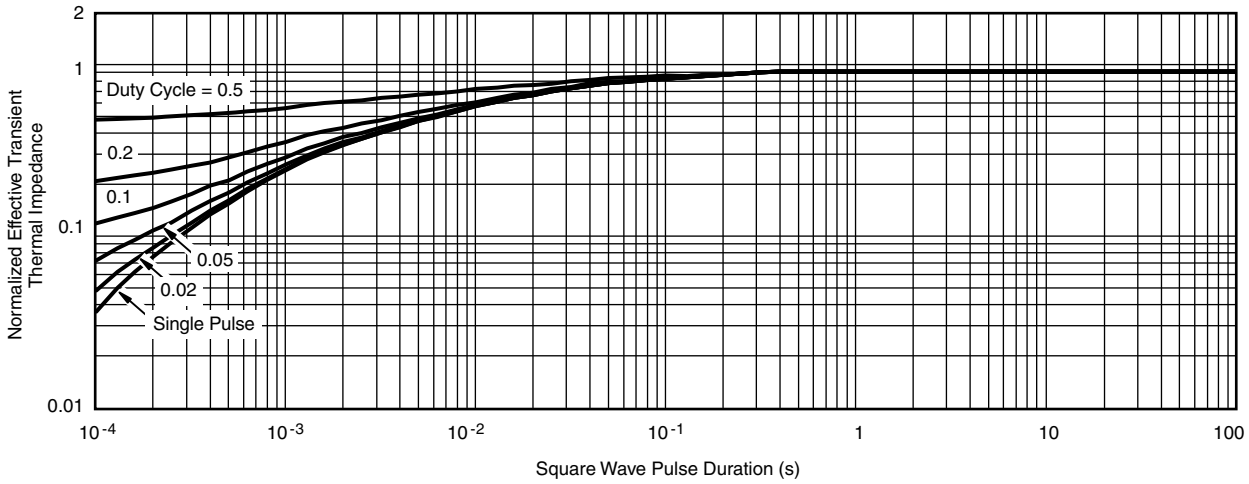

**Safe Operating Area**




**Normalized Thermal Transient Impedance, Junction-to-Ambient**


For technical questions, contact: automostechsupport@vishay.com
THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT www.vishay.com/doc?91000

## THERMAL RATINGS ($T_A$ = 25 °C, unless otherwise noted)




**Normalized Thermal Transient Impedance, Junction-to-Case**

**Note**

- The characteristics shown in the two graphs
  - Normalized Transient Thermal Impedance Junction-to-Ambient (25 °C)
  - Normalized Transient Thermal Impedance Junction-to-Case (25 °C)

  are given for general guidelines only to enable the user to get a “ball park” indication of part capabilities. The data are extracted from single pulse transient thermal impedance characteristics which are developed from empirical measurements. The latter is valid for the part mounted on printed circuit board - FR4, size 1" x 1" x 0.062", double sided with 2 oz. copper, 100 % on both sides. The part capabilities can widely vary depending on actual application parameters and operating conditions.

*Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see www.vishay.com/ppg?69060.*


For technical questions, contact: automostechsupport@vishay.com
THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT www.vishay.com/doc?91000

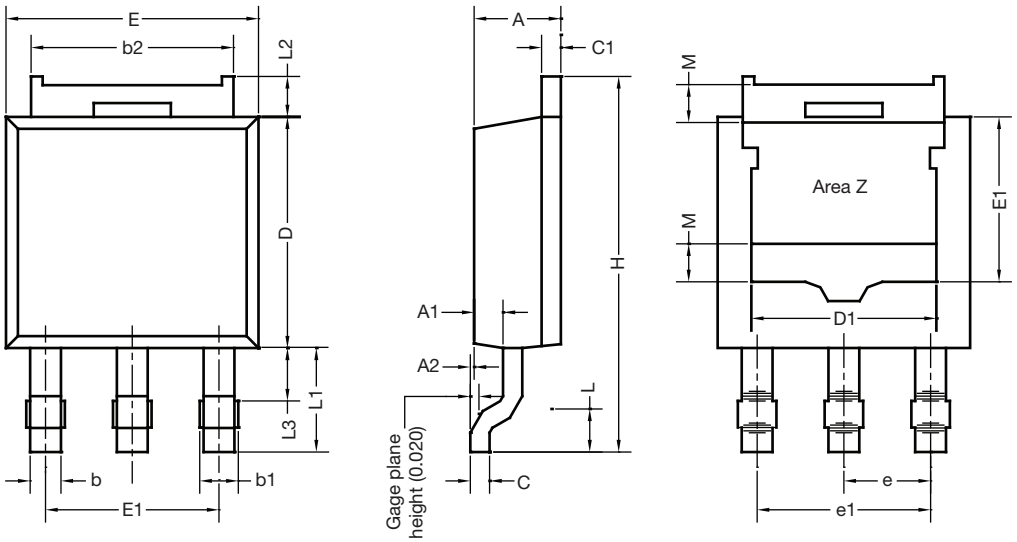
| REVISION HISTORY [a] | | |
|---|---|---|
| REVISION | DATE | DESCRIPTION OF CHANGE |
| F | 04-Aug-15 | • Revised $R_g$ minimum limit |

**Note**

a. As of April 2014


For technical questions, contact: automostechsupport@vishay.com
THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT www.vishay.com/doc?91000

# TO-252 Reverse Lead Case Outline




**Notes**

- Dimension L3 for reference only
- Area Z: unplated area more than 80 % heatsink area and for partial plating part only

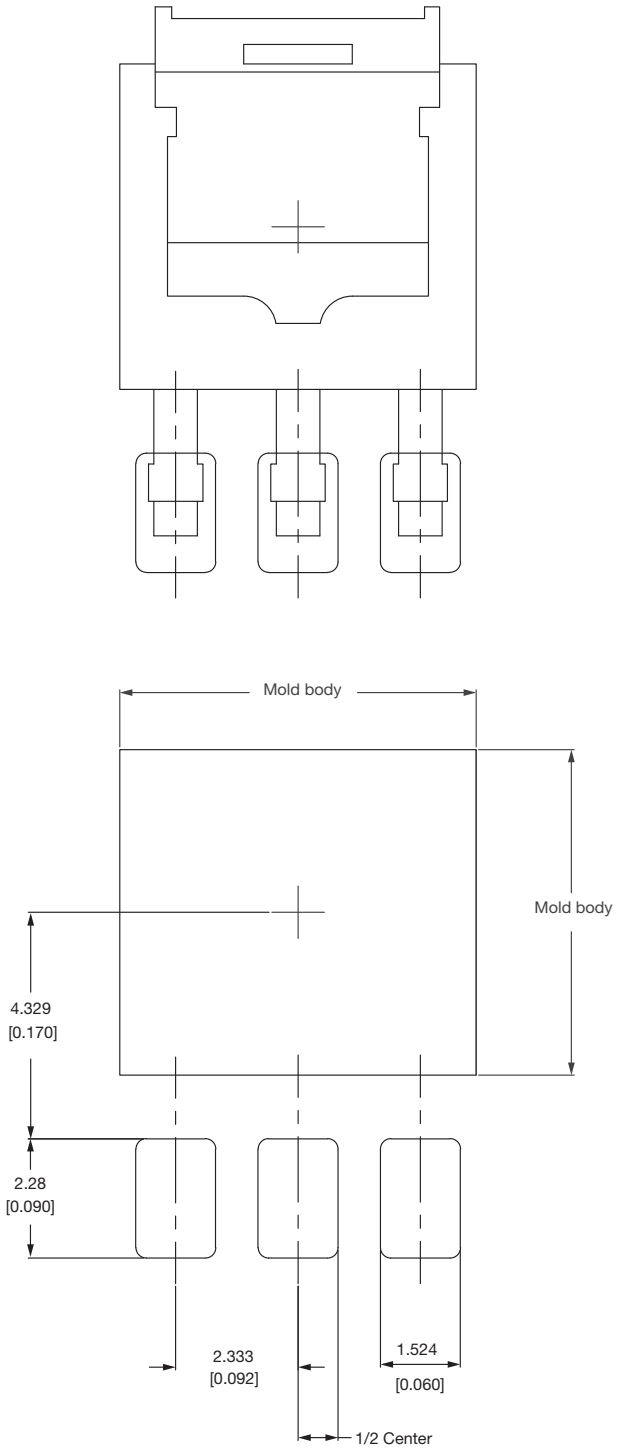
| DIM. | MILLIMETERS | | INCHES | |
|---|---|---|---|---|
| | MIN. | MAX. | MIN. | MAX. |
| A | 2.23 | 2.33 | 0.088 | 0.092 |
| A1 | 0.64 | 0.89 | 0.025 | 0.035 |
| A2 | 0.03 | 0.18 | 0.001 | 0.007 |
| b | 0.71 | 0.88 | 0.028 | 0.035 |
| b1 | 0.76 | 1.14 | 0.030 | 0.045 |
| b2 | 5.23 | 5.44 | 0.206 | 0.214 |
| C | 0.46 | 0.58 | 0.018 | 0.023 |
| C1 | 0.46 | 0.58 | 0.018 | 0.023 |
| D | 5.97 | 6.22 | 0.235 | 0.245 |
| D1 | 4.49 | 5.00 | 0.177 | 0.197 |
| E | 6.48 | 6.73 | 0.255 | 0.265 |
| E1 | 4.32 | - | 0.170 | - |
| e | 2.28 BSC | | 0.090 BSC | |
| e1 | 4.57 BSC | | 0.180 BSC | |
| H | 9.65 | 10.41 | 0.380 | 0.410 |
| L | 1.40 | 1.78 | 0.055 | 0.070 |
| L1 | 2.74 BSC | | 0.108 BSC | |
| L2 | 0.89 | 1.27 | 0.035 | 0.050 |
| L3 | 1.15 | 1.52 | 0.040 | 0.060 |
| M | - | 1.00 (reference only) | - | 0.039 (reference only) |
| ECN: T16-0952-Rev. D, 16-Jan-17<br>DWG: 5894 | | | | |



For technical questions, contact: pmostechsupport@vishay.com

THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT www.vishay.com/doc?91000

# Recommended Land Pattern DPAK (TO-252) 3LR




**Note**

- Dimensions in mm (inches)

ECN: T22-0575-Rev. A, 12-Dec-2022
DWG: 3015



For technical questions, contact: pmostechsupport@vishay.com

THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT www.vishay.com/doc?91000

# Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, “Vishay”), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Hyperlinks included in this datasheet may direct users to third-party websites. These links are provided as a convenience and for informational purposes only. Inclusion of these hyperlinks does not constitute an endorsement or an approval by Vishay of any of the products, services or opinions of the corporation, organization or individual associated with the third-party website. Vishay disclaims any and all liability and bears no responsibility for the accuracy, legality or content of the third-party website or for that of subsequent links.

Vishay products are not designed for use in life-saving or life-sustaining applications or any application in which the failure of the Vishay product could result in personal injury or death unless specifically qualified in writing by Vishay. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.

***© 2024 VISHAY INTERTECHNOLOGY, INC. ALL RIGHTS RESERVED***



THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT www.vishay.com/doc?91000